HD14519B

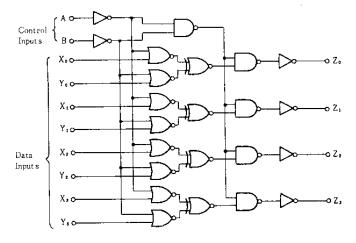
4-bit AND/OR Selector or Quadruple 2-Channel Data Selector or Quadruple Exclusive-NOR Gate

The HD14519B finds primary use where low power dissipation and/or high noise immunity is desired. This device exemplifies the design versatility of CMOS logic structure. This part provides three functions in one package; a 4-bit AND/OR Selector, a Quad 2-channel Data Selector, or a Quad Exclusive NOR Gate.

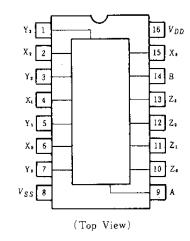
■ FEATURES

- Quiescent Current = 5nA/pkg typ. @5V
- Noise Immunity = 45% of V_{DD} typ.
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Compatible with HD14519B.

■LOGIC DIAGRAM



■ PIN ARRANGEMENT

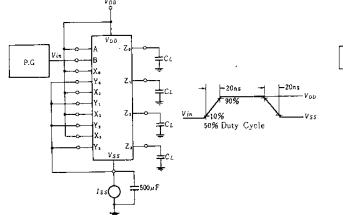


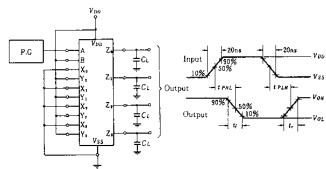
TRUTH TABLE

Contro	l Inputs	Outputs		
A	В	Zn		
0	0	0		
0	1	Yn		
1	0	Xn		
1	1	Xn⊕Yn		

■ POWER DISSIPATION TEST CIRCUIT AND WAVEFORM

SWITCHING TIME TEST CIRCUIT





■ ELECTRICAL CHARACTERISTICS

Characteristic S	Symbol	Test Conditions		-40°C		25°C			85°C		**	
Sharacteristic Symbo		$V_{DD}(V)$ lest Conditions		min	max	min	typ	max	min	max	Unit	
Output Voltage		5.0			0.05	_	0	0.05	_	0.05	v	
	Vol	10	$V_{in}=V_{DD}$ or $oldsymbol{0}$	_	0.05	-	0	0.05	_	0.05		
		15		_	0.05	-	0	0.05	_	0.05		
		5.0		4.95	_	4.95	5.0	_	4.95	-	v	
	V _{OH}	10	$V_{in}\!=\!0$ or V_{DD}	9.95	-	9.95	10	_	9.95	_		
		15		14.95	-	14.95	15	_	14.95	_		
-		5.0	$V_{out} = 4.5 \text{ or } 0.5V$	$V_{out} = 4.5 \text{ or } 0.5V$ - 1.5 - 2.25		1.5	_	1.5				
	V_{IL}	10	$V_{out}=9.0$ or $1.0\mathrm{V}$		3.0	_	4.50	3.0	-	3.0	V	
Input Voltage		15	Vout = 13.5 or 1.5V - 4.0 - 6.75 4.6		4.0		4.0					
		5.0	$V_{\text{out}} = 0.5 \text{ or } 4.5\text{V}$	3.5	_	3.5	2.75	_	3.5	-	v	
	V_{IH}	10	$V_{out} = 1.0 \text{ or } 9.0 \text{V}$	7.0		7.0	5.50		7.0	_		
		15	$V_{out} = 1.5 \text{ or } 13.5\text{V}$	11.0	_	11.0	8.25	_	11.0	_		
Output Drive Current		5.0	$V_{OH}=2.5V$	-1.0	_	-0.8	-1.7	_	-0.6		mA	
	J	5.0	$V_{OH} = 4.6 \text{V}$	-0.2		-0.16	-0.36	_	-0.12	_		
	Іон	10	$V_{OH}=9.5V$	-0.5	_	-0.4	-0.9		-0.3	_		
		15	$V_{OH} = 13.5 \text{V}$	-1.4		-1.2	-3.5	_	-1.0			
		5.0	$V_{OL}=0.4V$	0.52		0.44	0.88	_	0.36	-	m A	
	IoL	10	$V_{OL}=0.5V$	1.3	_	1.1	2.25	_	0.9			
		15	$V_{OL} = 1.5 \text{V}$	3.6	_	3.0	8.8	_	2.4	_		
Input Current	Iin	15	· · · · · · · · · · · · · · · · · · ·	_	±0.3	_	±0.00001	±0.3	_	±1.0	μA	
Input Capacitance	Cin		$V_{in} = 0$	-	<u> </u>	_	5.0	7.5	_	_	pF	
Quiescent Current I		5.0	7 () 1		20	_	0.005	20	_	150	μA	
	I_{DD}	10	Zero Signal,	_	40	_	0.010	40		300		
		15	per Package	_	80	_	0.015	80	***	600		
Total Supply Current*		5.0	Dynamic $+I_{\scriptscriptstyle DD}$,	-	-	-	1.2		-	— ,	μΑ	
	I_T	10	$C_L = 50 \text{pF}, f = 1 \text{ kHz}$	_	_	_	2.4	_	_	_		
		15	per Gate	_	_		3.6	_	_	_		
Three-State Output Leakage Current	ITL	15		_	±1.0	_	±0.00001	±1.0	_	±7.5	μA	

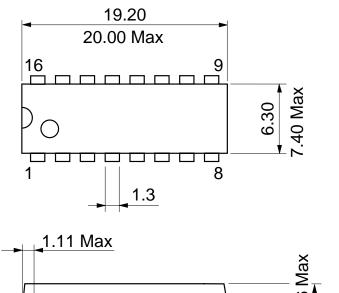
^{*} To calculate total supply current at frequency other than 1kHz.

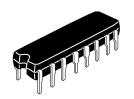
■SWITCHING CHARACTERISTICS $(C_L=50 \text{pF}, Ta=25 ^{\circ}\text{C})$

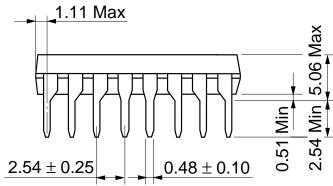
Characteristic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit	
Output Rise Time		5.0	_	180	400		
	t-	10		90	200	ns	
		15		65	160		
Output Fall Time	t f	5.0	_	100	200	ns	
		10	_	50	100		
		15	_	37	80		
Propagation Delay Time	tplн	5.0		250	500		
		10		115	225	ns	
		15		90	165		
	tpHL	5.0		250	500		
		10	_	115	225	ns	
		15		90	165		

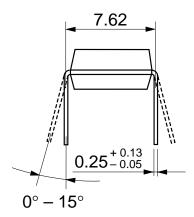
 $[@]V_{00} = 5.0V \\ I_{7} = (1.2\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 10V \\ I_{7} = (2.4\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ I_{7} = (3.6\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ I_{7} = (3.6\mu\text{A/kHz})f + I_{00} \\ @V_{00} = 15V \\ O(10) = 15V \\ O($

Unit: mm









Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

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